

IIT MADRAS Technology Transfer Office TTO - IPM Cell



Industrial Consultancy & Sponsored Research (IC&SR)

### Method & Apparatus for modifying dimensions of a waveguide **IITM Technology Available for Licensing**

#### **PROBLEM STATEMENT**

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- The challenge associated with small crosssection waveguides are the uniformity over large propagation lengths, core-cladding interface roughness and overall fabrication reproducibility.
- In the conventional art, the problem arising of the local refractive index trimming techniques cannot modify the dimensions of the waveguide during a design phase.
- Hence, there is a need to address the issues.
- Present invention provide the solution in efficient manner by providing the modified dimensions of a wavequide.

#### INTELLECTUAL PROPERTY

IITM IDF Ref. 1301; IN Patent No: 469080 US Patent No. US10168479 (Granted)

TECHNOLOGY CATEGORY/ MARKET

for Technology: Apparatus modifying dimensions of a waveguide;

Industry & Application: Photonic Devices, Optical interconnect devices, Optical Fibre, Semiconductor;

Market: The global optical waveguide market is projected to grow at a CAGR of 13.87% during 2024-2029.

#### TRL (TECHNOLOGY READINESS LEVEL)

TRL-4, Proof of Concept ready, tested in lab.

#### **TECHNOLOGY**

- Present invention describes a method & apparatus for modifying dimensions of a waveguide.
- The method few comprising а steps illustrated hereinbelow:

## 1<sup>St</sup> Step

Positioning a shadow mask with an aperture above the waveguide fabricated on a substrate.

#### **CONTACT US**

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#### **IITM TTO Website**: https://ipm.icsr.in/ipm/

#### 2<sup>nd</sup> Step

• Spatially filtering a substance, by the apparatus through the aperture of the shadow mask on a portion of the waveguide, wherein the **substance** is a vaporizing material deposited with the portion of the waveguide to modify a cladding of the waveguide; and

# 3<sup>rd</sup> Step

**Obtaining** an adiabatic spot size converter at end of the waveguide, by adjusting a distance between the shadow mask and the portion of the waveguide, to modify the dimensions of the waveguide. (Refer Fig.1)

#### **Process Flow Diagram**

Position a shadow mask, with an aperture, above the waveguide fabricated on a substrate

Spatially filter a substance through the aperture in the shadow mask on a portion of the waveguide

Obtain an adiabatic spot size converter at end of the waveguide by adjusting a distance between the shadow mask and a surface of the waveguide to modify the dimensions of the waveguide

Fig.1

#### **RESEARCH LAB**

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#### **TECHNOLOGY** (Contd.)

- Further for the apparatus modifying dimensions of a waveguide is illustrated herein. (Refer Fig. 2A-2F)
- The apparatus comprises one of a reactive ion etching system & a deposition system.
- Further, said apparatus includes a shadow mask which is with an aperture positioned wavequide, above the configured to spatially filter a substance through the aperture in the shadow mask on a portion of the waveguide.
- Furthermore, an adiabatic spot size converter is obtained at end of the waveguide.

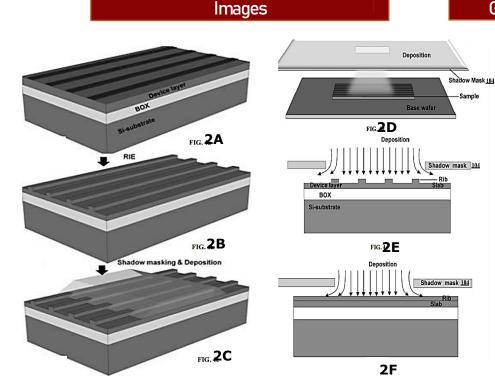
# **KEY FEATURES / VALUE PROPOSITION**

#### \* Technical Perspective:

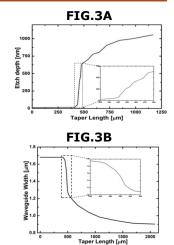
- dimensions The core are reduced adiabatically.
- The length of uniformly trimmed waveguide section is controlled by adjusting the length of the shadow mask aperture alone.
- Provide modified dimensions of waveguide which plays a vital role in terms of light coupling efficiency, effective refractive dispersion index, characteristics, mode-size simultaneously at any desired location of pre-defined single mode silicon-on-insulator (SOI) waveguide.

#### \* Industry Perspective:

- Easily fabricated on a substrate.
- Applicable both silicon platform & all planar light-wave circuits.



#### **Graphical Representation**



FIGs.3A, 3B: Illustrates the schematic representations for measured etch depth & width variation of a spotsize converter (SSC).

Fig. 2a to 2f represents a process flow for fabrication of the waveguide & deposition of a vaporized material on a waveguide cladding with an adiabatic vertical tapering at both ends of the waveguides;

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